
State-of-the-Art Program on Compound Semiconductors 56 (SOTAP0CS 56)

Editors:

J.-H. He

National Taiwan University
Taipei, Taiwan

C. Jagadish

The Australian National University
Canberra, Australia

C. O'Dwyer

University College Cork
Cork, Ireland

Y.-L. Chueh

National Tsing Hua University
Hsinchu City, Taiwan

F. Ren

University of Florida
Gainesville, Florida, USA

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Table of Contents

Preface	iii
Recent Advances in Semiconductor Nanowire Heterostructures <i>H. E. Jackson, L. M. Smith, C. Jagadish</i>	1
Integration of Photodefinable Polybenzoxazole as Intermetal Dielectric for GaAs HBT Technology <i>J. Yota, B. Do</i>	7
Behaviors of Carbon Atoms during Plasma Oxidation of 4H-SiC(0001) Surfaces near Room Temperature <i>N. Saito, D. Mori, A. Imafuku, K. Kawai, Y. Sano, M. Morita, K. Arima</i>	23
New Approaches to Realizing High Power Nitride Based Field Effect Transistors <i>M. Shur, G. Simin, R. Gaska</i>	29
Simulation of Radiation Damage in GaN HEMT Structures <i>E. Patrick, M. Choudhury, M. E. Law</i>	35
Low Power Zinc-Oxide Based Charge Trapping Memory with Embedded Silicon Nanoparticles <i>A. Nayfeh, A. Okyay, N. El-Atab, A. Ozcan, S. Alkis</i>	45
Topological Insulator Bi ₂ Se ₃ Nanowire Field Effect Transistors <i>H. Zhu, E. Zhao, C. A. Richter, Q. Li</i>	51
A Quick and a Flexible Hydride Vapor Phase Epitaxy Process to Achieve Buried Heterostructure Quantum Cascade Lasers <i>W. Metaferia, B. Simozrag, C. Junesand, Y. T. Sun, M. Carras, S. Lourdudoss</i>	61

III-V Nanowire MOSFETs in RF-Applications

69

L. E. Wernersson

Author Index

75